

# RGO-wrapped ZnS-SnS<sub>2</sub> Heterojunction Bimetallic Hollow Cubic Boxes as High Magnification and Long Lifespan Supercapacitor Anode Materials

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## Supplementary information

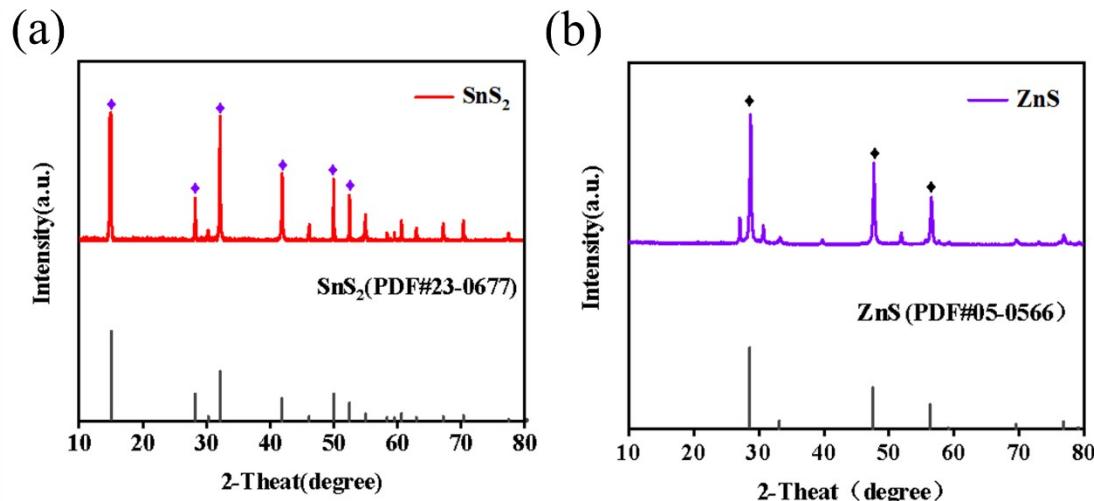
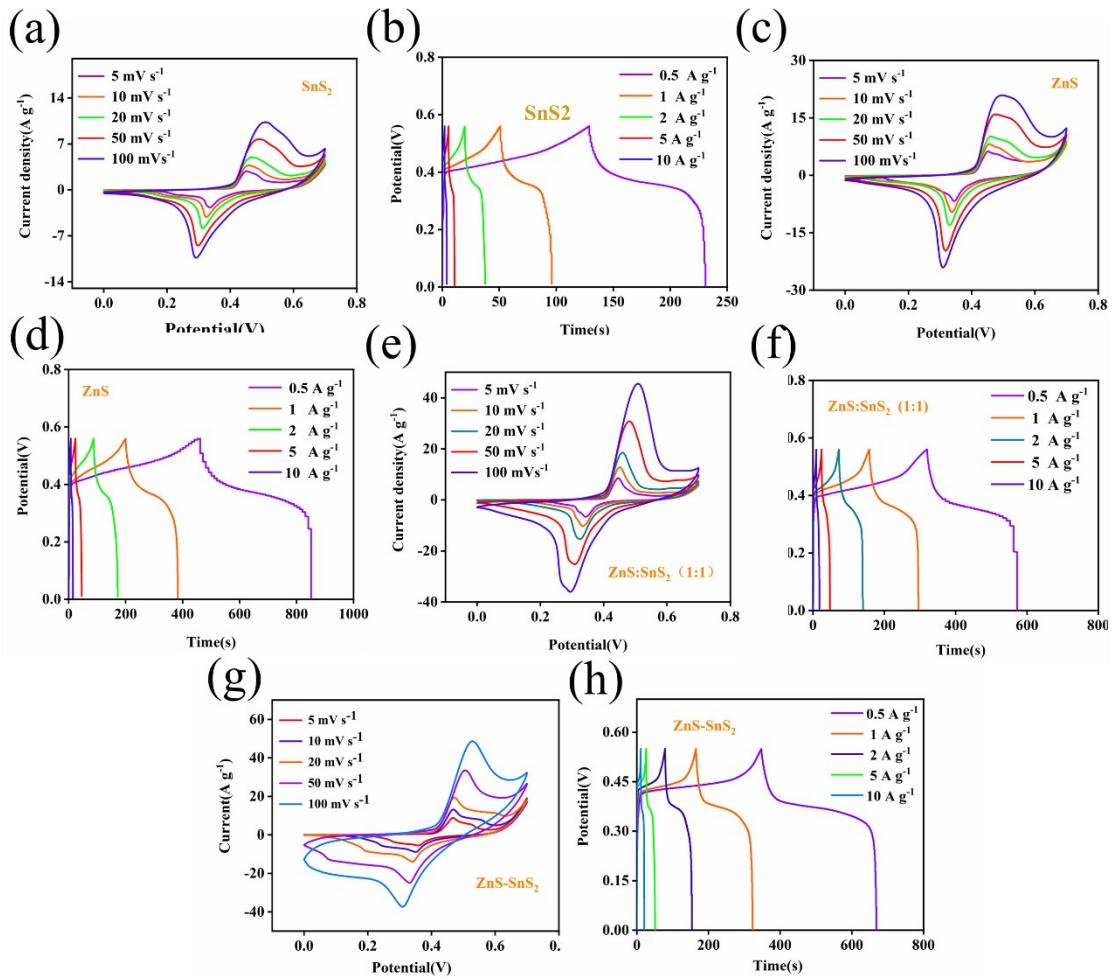
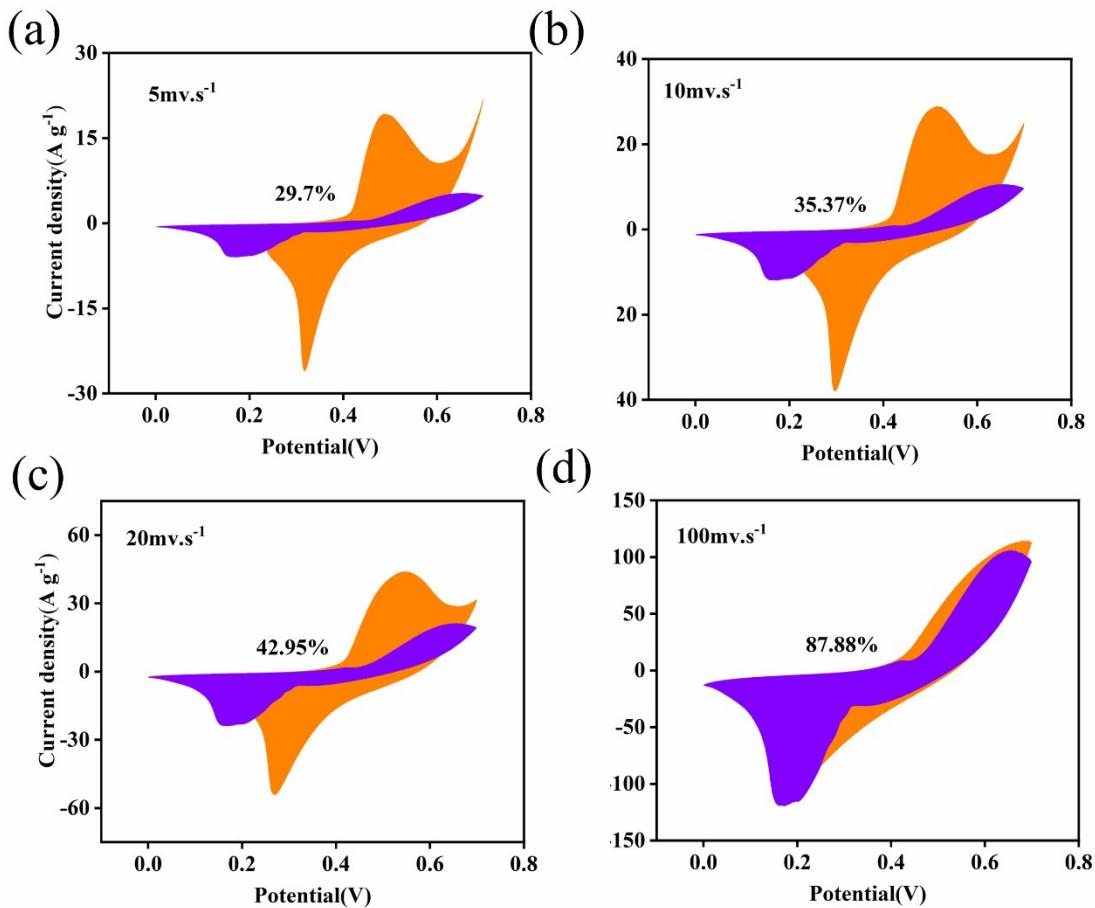


Fig.S1. (a) XRD image of SnS<sub>2</sub>. (b) XRD image of ZnS.

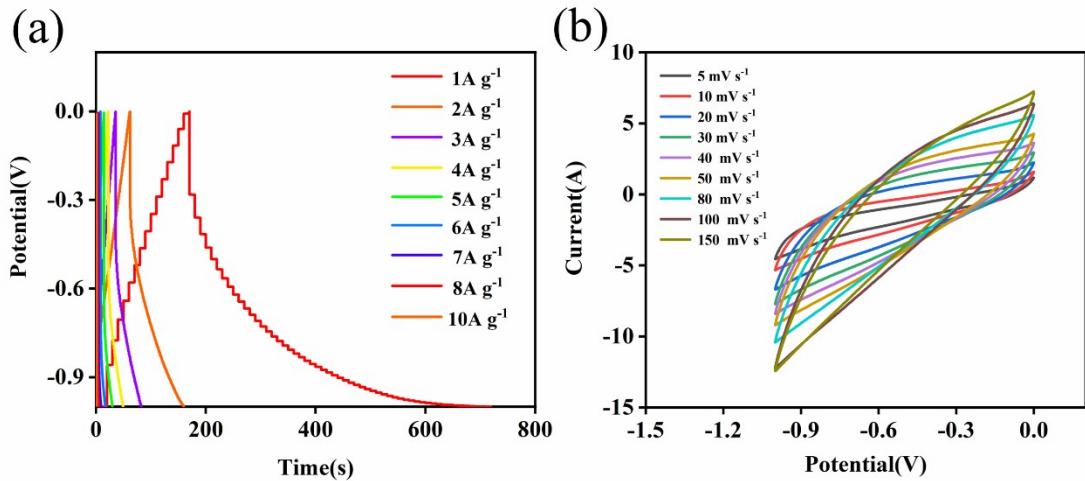
The diffraction peaks at 14.95°, 28.21°, 31.12°, 41.88°, 49.95° and 52.44° in Fig.S2a are consistent with (001), (100), (101), (102), (110) and (111) of SnS<sub>2</sub> plane related. In Fig.S2b, the diffraction peaks at 28.72°, 47.68°, and 56.51° are related to the (111), (220), and (311) planes of ZnS, respectively.



**Fig.S2. (a) CV curve and (b) GCD curve of SnS<sub>2</sub> material. (c) CV curve and (d) GCD curve of ZnS material. (e) CV curve and (e) CV curve of ZnS:SnS<sub>2</sub>(1:1) material( f) GCD curve. (g) CV curve and (h)GCD curve of ZnS-SnS<sub>2</sub> material.**



**Fig.S3.** Percentage of capacitive control at (a)  $5 \text{ mV.s}^{-1}$ , (b)  $10 \text{ mV.s}^{-1}$ , (c)  $20 \text{ mV.s}^{-1}$  and  $100 \text{ mV.s}^{-1}$  sweep rates.



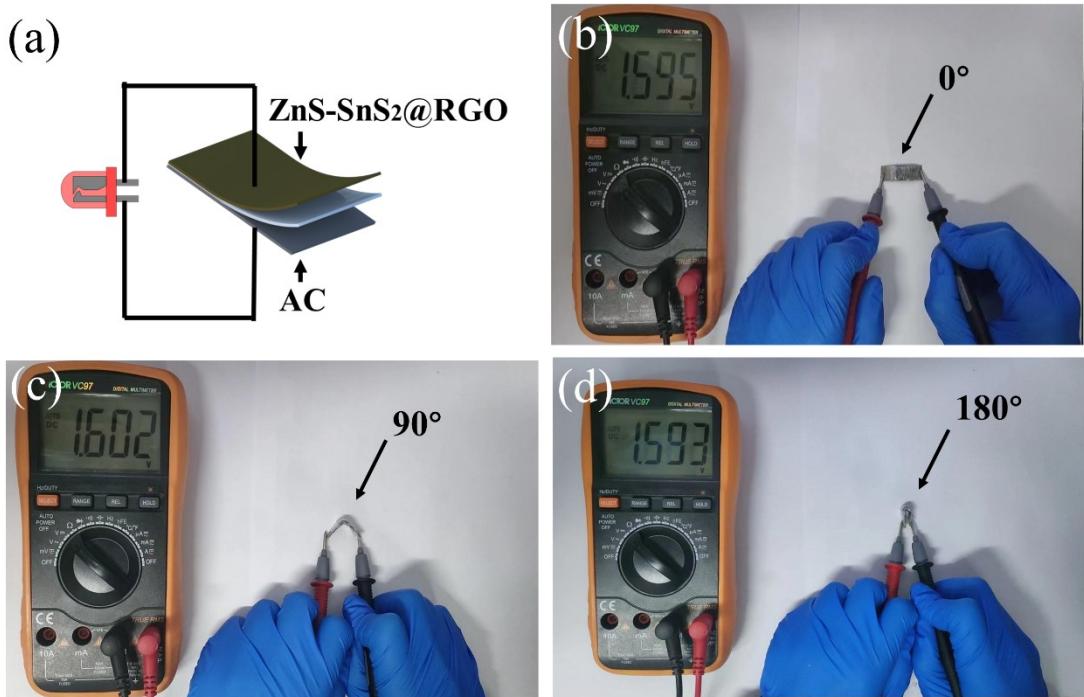
**Fig.S4:** (a) GCD curves of AC electrode at different current densities (b) CV curves of AC electrode at different scan speeds.

**Table S1**

**Comparison of ZnS-SnS<sub>2</sub>@RGO//AC with other ZnS,SnS<sub>2</sub> related devices.**

Materials	Specific capacitance	Current density or scan rate	Electrolyte	References
Ni/SnS <sub>2</sub> @Ni(OH) <sub>2</sub> -CC	$158.1 \text{ mAh.g}^{-1}$	$0.5 \text{ A g}^{-1}$	PVA-KOH	[1]

$\text{SnS}_2/\text{mK-BN/CNT}$	$87 \text{ F.g}^{-1}$	$2\text{A.g}^{-1}$	1M TEABF <sub>4</sub>	[2]
$\text{SnS}_2/\text{rGO}$	$92.4 \text{ F.g}^{-1}$	$1\text{A.g}^{-1}$	1M NaOH	[3]
Mn-doped ZnS	$98 \text{ F.g}^{-1}$	$1\text{A.g}^{-1}$	3M KOH	[4]
$\text{g-C}_3\text{N}_4/\text{ZnS}$	$92.8 \text{ F.g}^{-1}$	$0.5\text{A.g}^{-1}$	6M KOH	[5]
ZnS-NiS <sub>1.97</sub> hollow spheres	$123.6\text{F.g}^{-1}$	$0.5\text{A.g}^{-1}$	3M KOH	[6]
ZnS NWs/Cu <sub>7</sub> S <sub>4</sub> NPs/rGO	$112 \text{ F.g}^{-1}$	$1\text{A.g}^{-1}$	6M KOH	[7]
porous carbon/ZnS	$82 \text{ F.g}^{-1}$	$1\text{A.g}^{-1}$	0.5M H <sub>2</sub> SO <sub>4</sub>	[8]
ZnS-SnS <sub>2</sub> @RGO	$52.5\text{F.g}^{-1}$	$1\text{A g}^{-1}$	PVA-KOH	This work



**Fig.S5. Schematic diagram of ASC device(a). Device voltages were measured after the ASC device was collapsed at 0° (b),90° (c),180° (d).**

## Reference

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